

Engineering/Process Change Notice

ECN/PCN No.: 4147

For Manufacturer						
Product Description: PLASTIC SMD MEMS OSCILLATOR	Abracon Part Numb	e r / Part Series: RB85	□ Documentation only□ ECN⋈ EOL	⊠ Series □ Part Number		
Affected Revision:	New Revision:	OL	Application:	☐ Safety ☑ Non-Safety		
Prior to Change: Active https://abracon.com/datasheets/Ecliptek/	EMRB85.pdf			,		
After Change: EOL Cause/Reason for Change:						
Discontinuation of manufacturing capability	ty.					
		ge Plan				
Effective Date: 2/7/2022	Additional Remarks: N/A					
Change Declaration: N/A						
Issued Date: 2/7/2022	Issued By: Brooke Cushman Product Engineer		Issued Department: Engineering			
Approval: Thomas Culhane Engineering Director	Approval: Reuben Quintanilla Quality Director		Approval: Ying Huang Purchasing Director			
	For Abrad	on EOL only				
Last Time Buy (if applicable): 5/7/2022	Alternate Part Num		per / Part Series: none			
Additional Approval:	Additional Approval:		Additional Approval:			
	Customer Appr	oval (If Applicable)				
Qualification Status: Note: It is considered approved if there is n		□ Not accepted sustomer 1 month afte	r ECN/PCN is released.			
Customer Part Number:		Customer Project:				
Company Name:	Company Represent	ative:	Representative Signature	:		
Customer Remarks:						

















REGULATORY COMPLIANCE











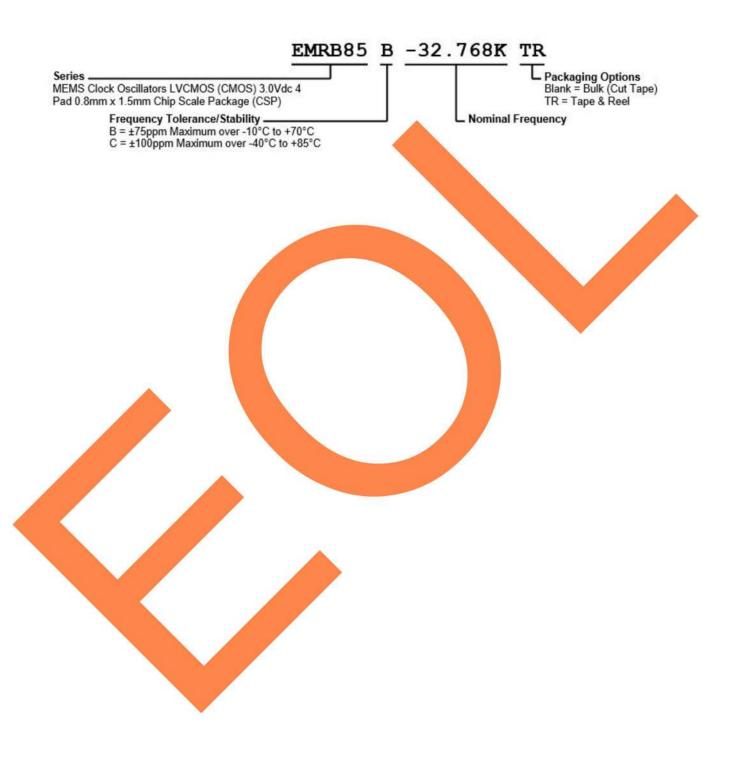
ITEM DESCRIPTION

MEMS Clock Oscillators LVCMOS (CMOS) 3.0Vdc 4 Pad 0.8mm x 1.5mm Chip Scale Package (CSP)

ELECTRICAL SPECIFICATIONS			
Nominal Frequency	32.768kHz		
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, and Output Load Change ±75ppm Maximum over -10°C to +70°C ±100ppm Maximum over -40°C to +85°C		
Frequency Tolerance	Measured at 25°C ±2°C, at Vdd=3.0Vdc, Post Reflow, with board level underfill ±20ppm Maximum		
Aging at 25°C	±1ppm Maximum First Year		
Supply Voltage	3.0Vdc ±10%		
Core Operating Current	0.9μA Typical (at 25°C), 1.4μA Maximum at Frequency Tolerance/Stability of ±100ppm Maximum over -40°C to +85°C 0.9μA Typical (at 25°C), 1.3μA Maximum at Frequency Tolerance/Stability of ±75ppm Maximum over -10°C to +70°C		
Output Stage Operating Current	0.065μΑ/Vpp Typical, 0.125μΑ/Vpp Maximum		
Input Current	No Load, Nom <mark>inal Vdd</mark> 1.1μA Typical (at 25°C), 1.9μA Maximum at Frequency Tolerance/Stability of ±100ppm Maximum over -40°C to +85°C 1.1μA Typical (at 25°C), 1.7μA Maximum at Frequency Tolerance/Stability of ±75ppm Maximum over -10°C to +70°C		
Output Voltage Logic High (Voh)	IOH = -10µA 90% of Vdd M <mark>inimum</mark>		
Output Voltage Logic Low (Voi)	IOL = +10µA 10% of Vdd Maximum		
Rise/Fall Time	Measured from 10% to 90% of waveform 100nSec Typical, 200nSec Maximum		
Duty Cycle	Measured at 50% of waveform 50 ±2(%)		
Load Drive Capability	15pF Maximum		
Output Logic Type	CMOS		
Period Jitter (RMS)	Measured at 25°C 35nSec Typical		
Power Supply Ramp	Measured at 0Vdc to 90% of Vdd 100mSec Maximum		
Start Up Time	Measured at Nominal Vdd 180mSec Typical, 300mSec Maximum (at 25°C) 450mSec Maximum (over Operating Temperature Range)		
Storage Temperature Range	-55°C to +125°C		

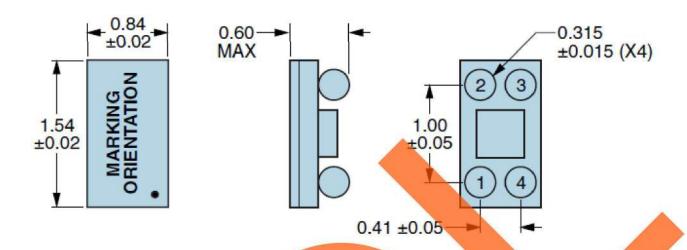


PART NUMBERING GUIDE

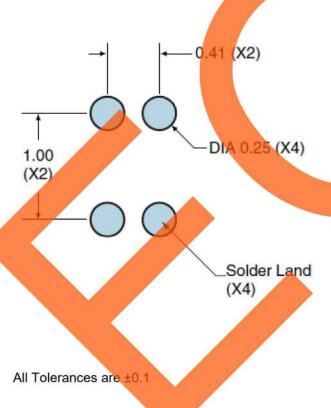




MECHANICAL DIMENSIONS



SUGGESTED SOLDER PAD LAYOUT

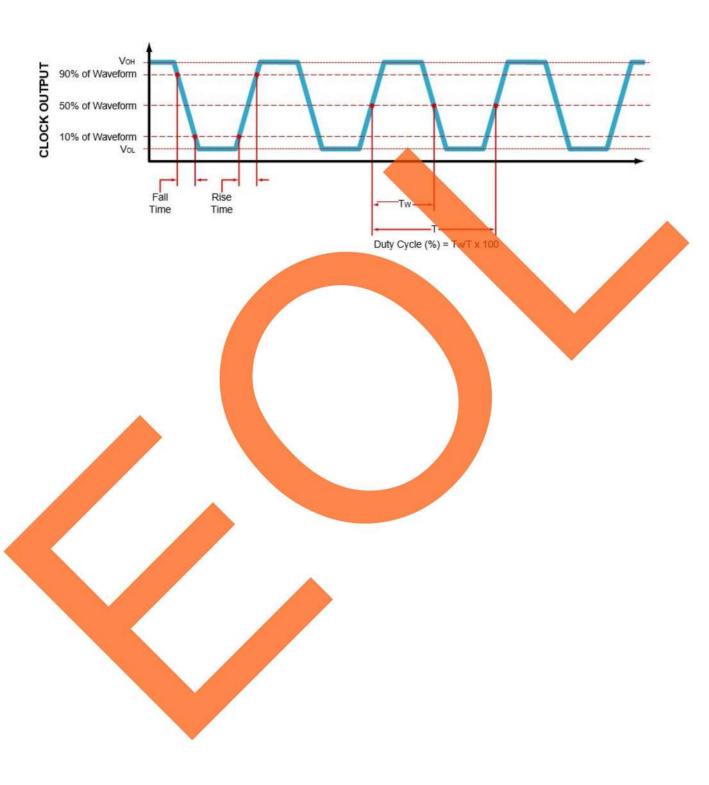


PIN	CONNECTION
1	Ground
2	Output
3	Supply Voltage
4	Ground

All Dimensions in Millimeters

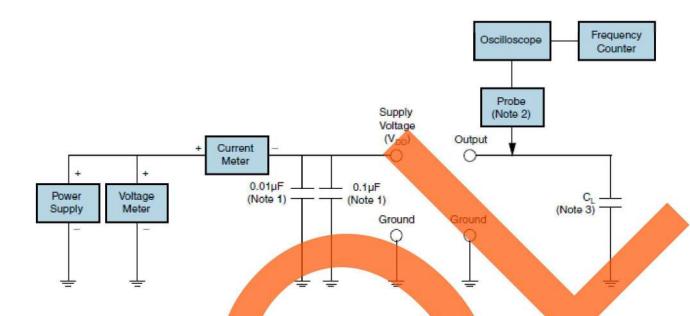


OUTPUT WAVEFORM & TIMING DIAGRAM





TEST CIRCUIT FOR CMOS OUTPUT



- Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less Than 2mm) to the package ground and supply voltage pin is required.

 Note 2: A low input capacitance (<12pF), 10X attentuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz)
- Note 2: A low input capacitance (<12pF), 10X attentuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) Passive probe is recommended.
- Note 3: Capacitance value CL includes sum of all probe and fixture capacitance. See applicable specification sheet for 'Load Drive Capability'.

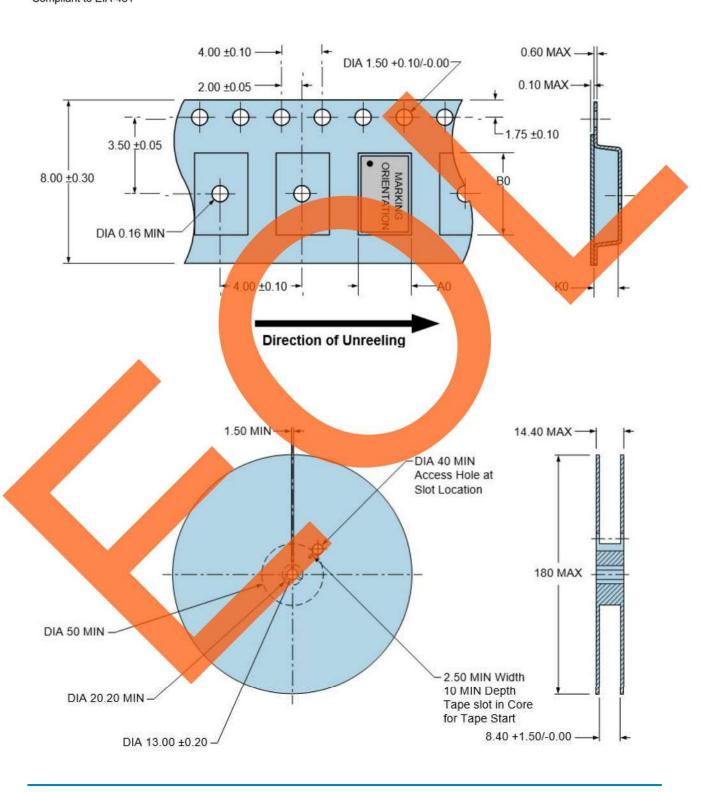


TAPE & REEL DIMENSIONS

Quantity per Reel: 3000 Units

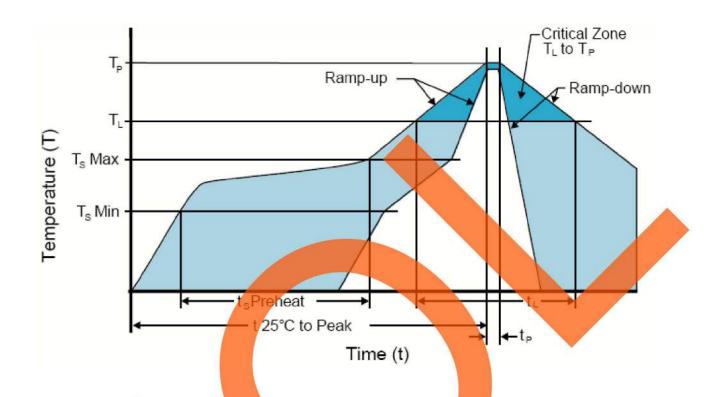
All Dimensions in Millimeters

Compliant to EIA-481





RECOMMENDED SOLDER REFLOW METHOD



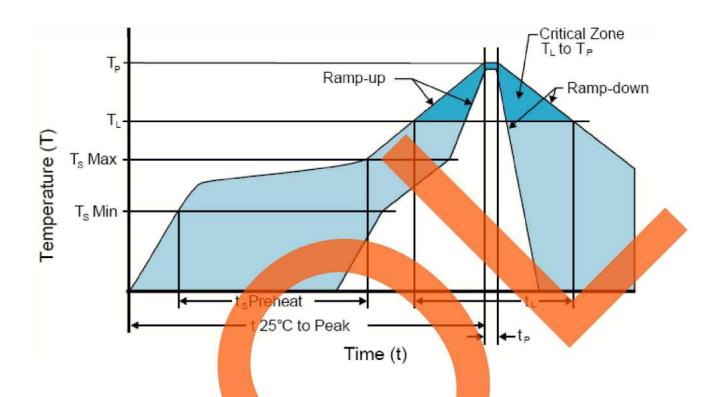
HIGH TEMPERATURE INFRARED/CONVECTION		
T _S MAX to T _L (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	150°C	
- Temperature Typical (T _S TYP)	175°C	
- Temperature Maximum(T _s MAX)	200°C	
- Time (t _s)	60 - 180 Seconds	
Ramp-up Rate (T _L to T _P)	3°C/Second Maximum	
Time Maintained Above:		
- Temperature (T _L)	217°C	
- Time (t _L)	60 - 150 Seconds	
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(Tp Target)	250°C +0/-5°C	
Time within 5°C of actual peak (t _p)	20 - 40 Seconds	
Ramp-down Rate	6°C/Second Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
- Temperature Minimum (T. MIN)	N/A	
- Temperature Typical (Ts TYP)	150°C	
- Temperature Maximum(T _s MAX)	N/A	
- Time (t _s)	60 - 120 Seconds	
Ramp-up Rate (T _L to T _P)	5°C/Second Maximum	
Time Maintained Above:		
- Temperature (T _L)	150°C	
- Time (t _L)	200 Seconds Maximum	
Peak Temperature (T _P)	240°C Maximum	
Target Peak Temperature (Te Target)	240°C Maximum 2 Times / 230°C Maximum 1 Time	
Time within 5°C of actual peak (tp)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5°C/Second Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)